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ON Semiconductor MBR3060RL

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Distributor of ON Semiconductor: Excellent Integrated System Limited Datasheet of MBR3060RL - DIODE SCHOTTKY 60V 3A AXIAL Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

MBR3060

Axial Lead Rectifier

... employing the Schottky Barrier principle in a large area metal-to-silicon power diode. State-of-the-art geometry features epitaxial construction with oxide passivation and metal overlap contact. Ideally suited for use as rectifiers in low-voltage, high-frequency inverters, free wheeling diodes, and polarity protection diodes.

- Extremely Low V_f
- Low Power Loss/High Efficiency
- Highly Stable Oxide Passivated Junction
- Low Stored Charge, Majority Carrier Conduction

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: 0.4 gram (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 220°C Max. for 10 Seconds, 1/16" from case
- Available Tape and Reeled, 5000 per reel, by adding a "RL" suffix to the part number
- Polarity: Cathode indicated by Polarity Band
- Machine Model = A• ESD Ratings: Human Body Model = 2
- Marking: MBR3060

MAXIMUM RATINGS

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Vr	,5		I	MBR3060 = Devi	ce
V _r	3.0	A	I	MBR3060 = Devi	ce
	3.0	A		MBR3060 = Devi	ce
	C	A		MBR3060 = Devi	ce
V _r l _o l _{FSM}	3.0 125	A		MBR3060 = Devi	
Vr lo I _{FSM}	125	A	OR	DERING INFO	
Vr lo	C		OR	DERING INFO	
Vr lo I _{FSM}	125	A	OR	DERING INFO	
Vr I _o I _{ESM} T _J , T _{stg}	125 -65 to +150	A °C	OR	DERING INFO	
Vr lo I _{FSM}	125	A	OR Device MBR3060	DERING INFO Package Axial Lead	
	perature for 5" from case bag per reel, by blarity Band l = A Aodel = 2	Trosion Resistant and Terperature for Soldering Pu $5''$ from case \cdot bagper reel, by adding a "Rblarity Band $1 = A$ Aodel = 2SymbolMaxVRRM60	rrosion Resistant and Terminal perature for Soldering Purposes: 5" from case bag per reel, by adding a "RL" suffi blarity Band 1 = A Aodel = 2 Symbol Max Unit	rrosion Resistant and Terminal perature for Soldering Purposes: "from case bag per reel, by adding a "RL" suffix to blarity Band 1 = A Aodel = 2 Symbol Max VRRM 60	Axial Left bag bag per reel, by adding a "RL" suffix to blarity Band 1 = A Axial Left Axial Left Case 59-0 PLASTIC MARKING DIA VRRM 60



ON Semiconductor™

http://onsemi.com

SCHOTTKY BARRIER RECTIFIER 3.0 AMPERES 60 VOLTS

MARKING DIAGRAM



MBR3060 = Device Code

ORDERING INFORMATION

Device	Package	Shipping		
MBR3060	Axial Lead	1000 Units/Bag		
MBR3060RL	Axial Lead	5000/Tape & Reel		



MBR3060

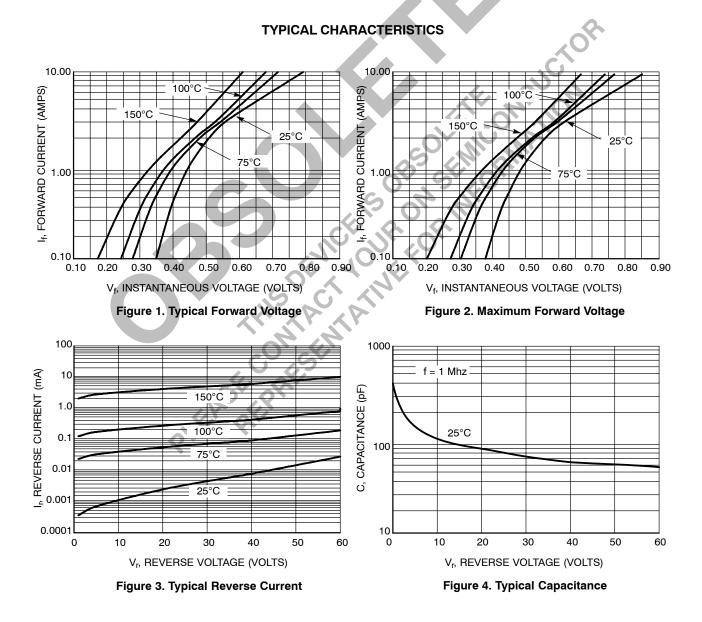
THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit			
Thermal Resistance, Junction-to-Lead (Note 1, see Note 3, Mounting Method 3)	R_{\thetaJL}	13	°C/W			
Thermal Resistance, Junction-to-Ambient (see Note 3, Mounting Method 3)	$R_{\theta JA}$	50	°C/W			
ELECTRICAL CHARACTERISTICS (T1 = 25°C unless otherwise noted) (Note 1)						

Characteristic	Symbol	Мах	Unit	
$\label{eq:linear} \begin{array}{l} \mbox{Maximum Instantaneous Forward Voltage (Note 2)} \\ (I_f = 3.0 \mbox{ Amp}), \mbox{ T}_L = 25^\circ \mbox{C} \\ (I_f = 3.0 \mbox{ Amp}), \mbox{ T}_L = 100^\circ \mbox{C} \end{array}$		V _f	0.62 0.59	V
Maximum Instantaneous Reverse Current (Note 2) $(V_r = 60 \text{ V}), \text{ T}_L = 25^{\circ}\text{C}$ $(V_r = 60 \text{ V}), \text{ T}_L = 100^{\circ}\text{C}$		I _r	150 10	μA mA

1. Lead Temperature reference is cathode lead at printed wiring board.

2. Pulse Test: Pulse Width = 300 μ s, Duty Cycle = 2.0%.

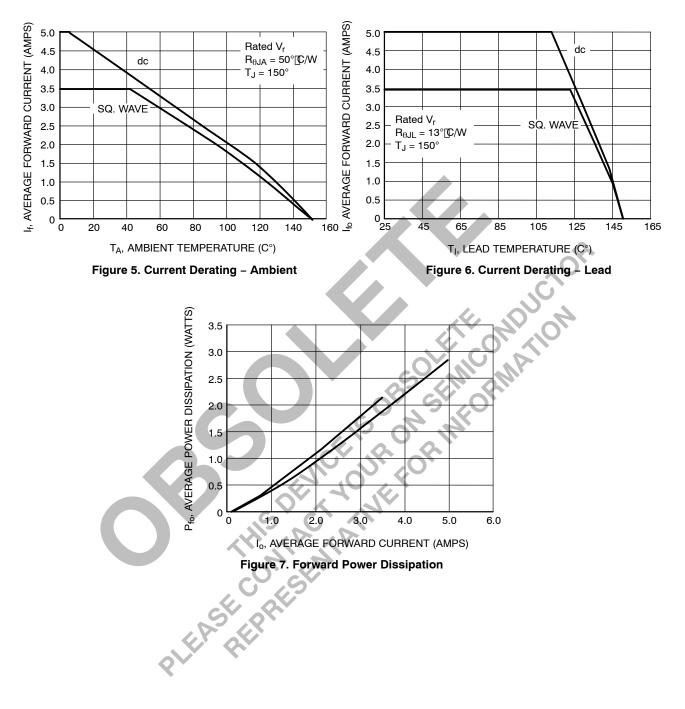




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TYPICAL CHARACTERISTICS





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NOTE 3 — MOUNTING DATA

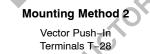
Data shown for thermal resistance junction-to-ambient ($R_{\theta JA}$) and thermal resistance junction-to-lead ($R_{\theta JL}$) for the mountings shown is to be used as typical guideline values for preliminary engineering, or in case the tie point temperature cannot be measured.

IT FICAL VALUES FOR $R_{\theta JA}$ IN STILL AIR					
Mounting	Lead Length, L (in)				
Method	1/8	1/4	1/2	3/4	$\mathbf{R}_{\theta \mathbf{JA}}$
1	52	65	72	85	°C/W
2	67	80	87	100	°C/W
3	50			°C/W	

TYPICAL VALUES FOR $R_{\theta,JA}$ IN STILL AIR

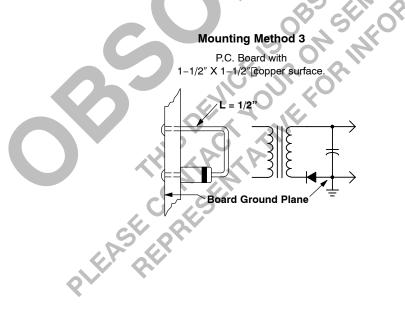
TYPICAL VALUES FOR $\textbf{R}_{\theta \textbf{JL}}$ IN STILL AIR

Mounting	Lead			
Method	1/8	1/4	1/2	$\mathbf{R}_{\theta \mathbf{JA}}$
1	15	23	37	°C/W
2	30	38	52	°C/W
3		°C/W		



Mounting Method 1

P.C. Board with $1-1/2'' \times 1-1/2''$ copper surface.

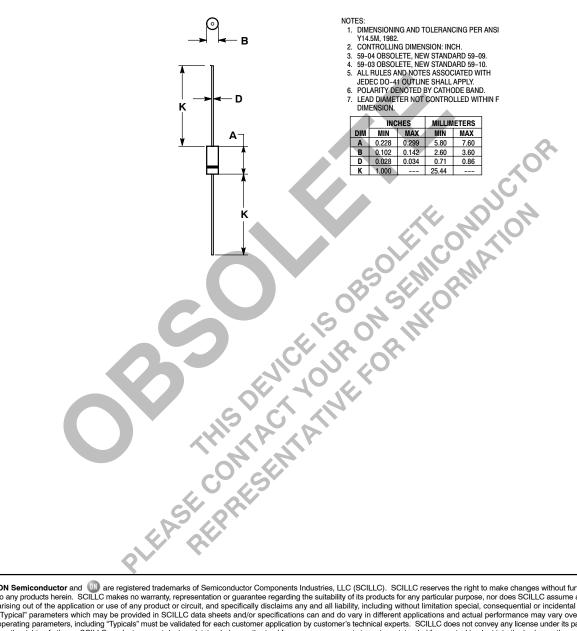




MBR3060

PACKAGE DIMENSIONS

AXIAL LEAD CASE 59–09 ISSUE R



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